## NSN 5961-01-090-1686

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View Online at https://aerobasegroup.com/nsn/5961-01-090-1686 **Inclosure Material:** Metal **Overall Length:** 1.573 inches **Overall Height:** 0.328 inches **Overall Width:** 1.050 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -80.0 collector to base voltage/static/emitter open and -5.0 emitter to base voltage, static, collector open and -80.0 collector to emitter voltage/static/base open **Current Rating Per Characteristic:** -12.00 amperes source cutoff current and -0.20 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-prf-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 81349-mil-prf-19500/501 government specification

**Unit Of Measure:** 

Demilitarization:

Shelf Life:

N/a

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Mil-std (military Standard):

Mil-prf-19500 spec.